

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

SEMICONDUCTOR DEVICE FORMED BY IN-SITU
MODIFICATION OF DIELECTRIC LAYER AND RELATED
METHODS

Application Number :

Confirmation Number:

First Named Applicant: William America

Attorney Docket Number: FIS920040083US1

Art Unit:

Examiner:

Search string: (6603204 or 6596655 or 6589888 or 6472231 or 6340435 or 6710450).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	6603204	2003-08-05	Gates et al			
	2	6596655	2003-07-22	Cheung et al			
	3	6589888	2003-07-08	Nemani et al			
	4	6472231	2002-10-29	Gabriel et al			
	5	6340435	2002-01-22	Bjorkman et al			
	6	6710450	2004-03-23	Gates et al			

Signature

Examiner Name	Date